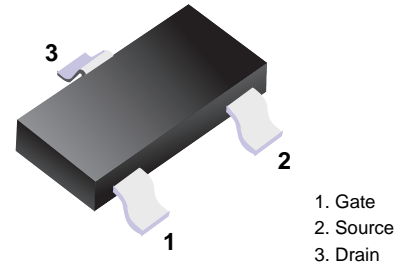


2SC3356

■ NPN Transistors

■ Features

- Low noise and high gain.
NF = 1.1 dB Typ., Ga = 11 dB Typ. @V_{CE} = 10 V, I_c = 7 mA, f = 1.0 GHz
- High power gain.
MAG = 13 dB Typ. @V_{CE} = 10 V, I_c = 20 mA, f = 1.0 GHz



■ Simplified outline(SOT23-3L)

■ Absolute Maximum Ratings Ta = 25°C

| Parameter | Symbol | Rating | Unit |
|------------------------------|------------------|-------------|------|
| Collector to base voltage | V _{CBO} | 20 | V |
| Collector to emitter voltage | V _{CEO} | 12 | V |
| Emitter to base voltage | V _{EBO} | 3.0 | V |
| Collector current (DC) | I _c | 100 | mA |
| Total power dissipation | P _{tot} | 200 | mW |
| Junction temperature | T _j | 150 | °C |
| Storage temperature range | T _{stg} | -65 to +150 | °C |

■ Electrical Characteristics Ta = 25°C

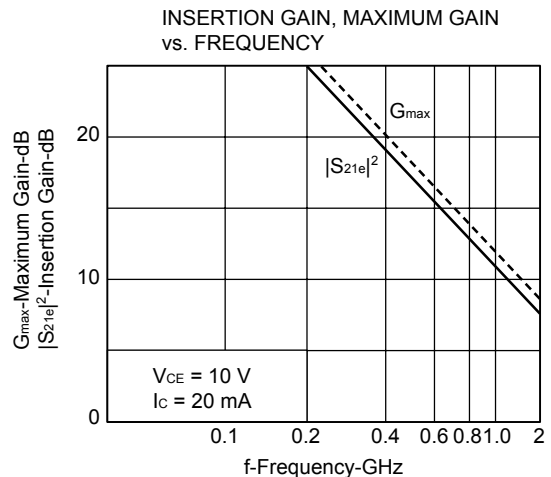
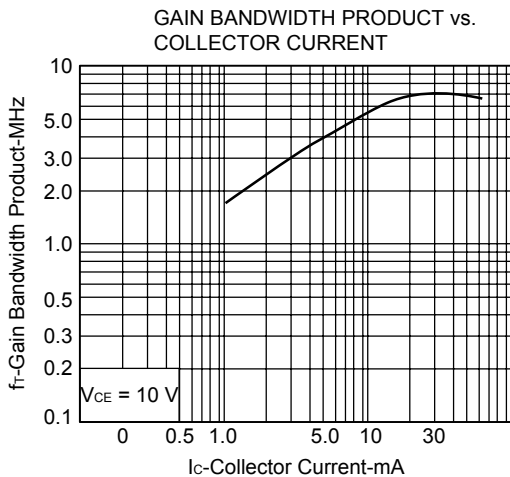
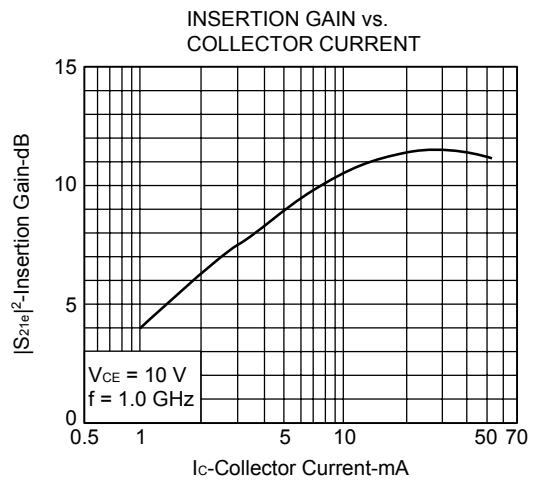
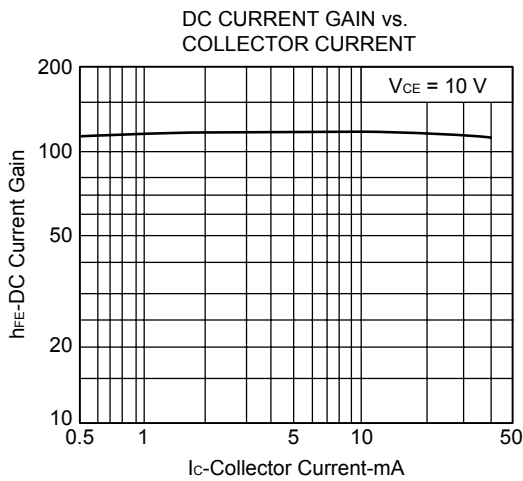
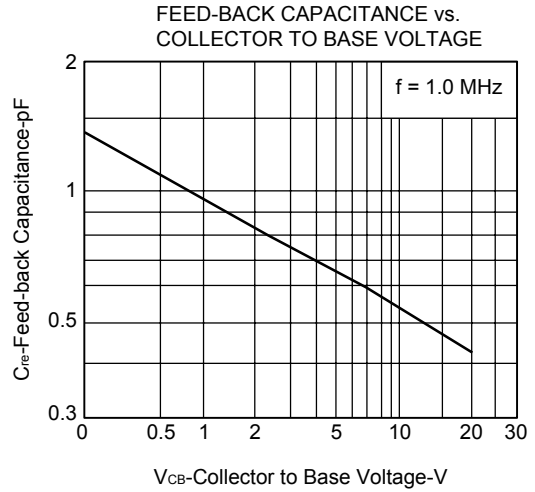
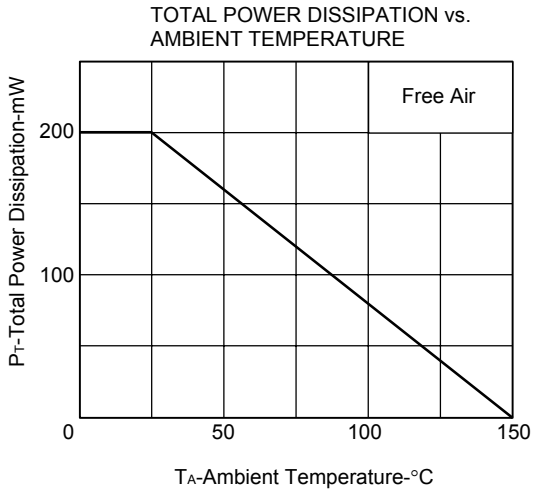
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|--|---------------------------------|---|-----|------|-----|------|
| Collector- base breakdown voltage | V _{CBO} | I _c = 100 μA, I _E = 0 | 20 | | | V |
| Collector- emitter breakdown voltage | V _{CEO} | I _c = 1 mA, I _B = 0 | 12 | | | |
| Emitter - base breakdown voltage | V _{EBO} | I _E = 100 μA, I _c = 0 | 3 | | | |
| Collector-base cut-off current | I _{CBO} | V _{CB} = 10 V, I _E = 0 | | | 1 | μA |
| Emitter cut-off current | I _{EBO} | V _{EB} = 3V, I _c =0 | | | 1 | |
| Collector-emitter saturation voltage * | V _{CE(sat)} | I _c =50 mA, I _B =5mA | | | 0.4 | V |
| Base - emitter saturation voltage * | V _{BE(sat)} | I _c =50 mA, I _B =5mA | | | 1.2 | |
| DC current gain * | h _{FE} | V _{CE} = 10V, I _c = 20mA | 50 | | 400 | |
| Insertion power gain | S _{21e} ² | V _{CE} = 10 V, I _c = 20 mA, f= 1GHz | | 11.5 | | dB |
| Noise figure | NF | V _{CE} = 10 V, I _c = 7 mA, f= 1GHz | | 1.1 | 2 | |
| Reverse transfer capacitance | C _{re} | V _{CB} = 10V, I _E = 0, f=1MHz | | 0.55 | 1 | pF |
| Transition frequency | f _r | V _{CE} = 10V, I _c = 20mA | | 7 | | GHz |

*. Pulse measurement: PW ≤ 350 μs, Duty Cycle ≤ 2%.

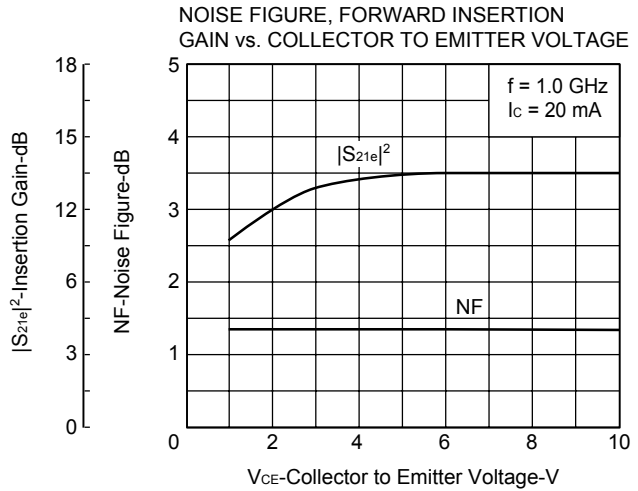
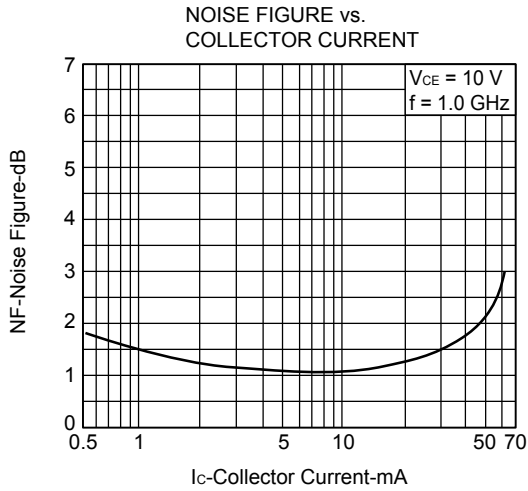
■ h_{FE} Classification

| Type | 2SC3356-R23 | 2SC3356-R24 | 2SC3356-R25 | 2SC3356-R26 |
|---------|-------------|-------------|-------------|-------------|
| Range | 50-100 | 80-160 | 125-250 | 250-400 |
| Marking | R23 | R24 | R25 | R26 |

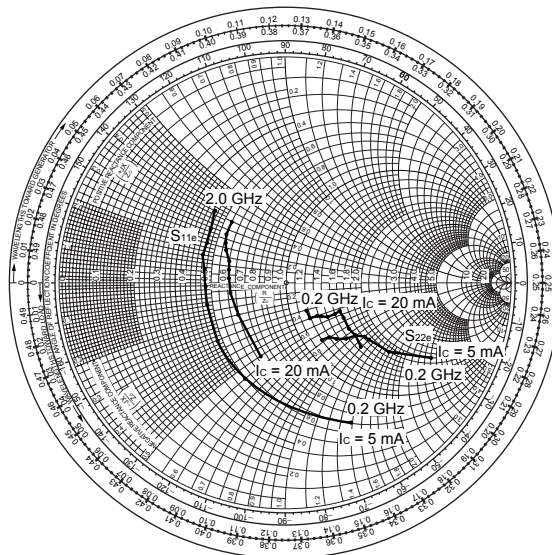
■ Typical Characteristics



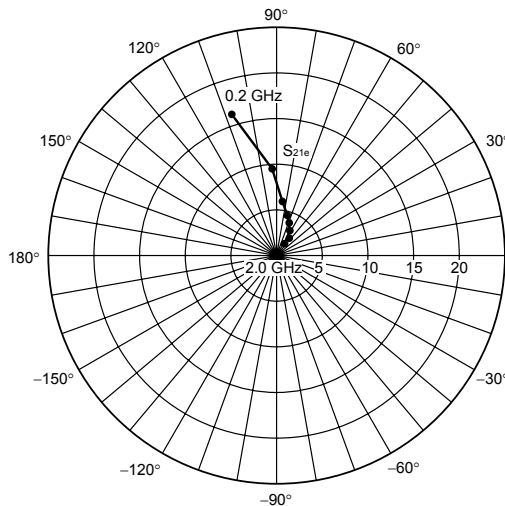
■ Typical Characteristics



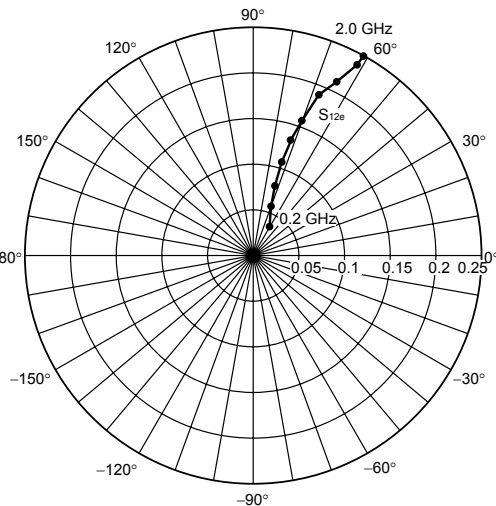
S_{11e}, S_{22e}-FREQUENCY
CONDITION $V_{CE} = 10\text{ V}$
200 MHz Step



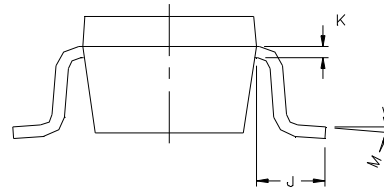
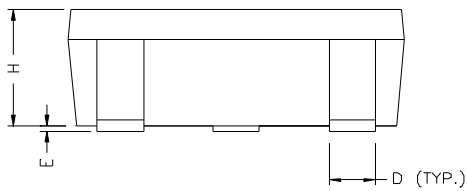
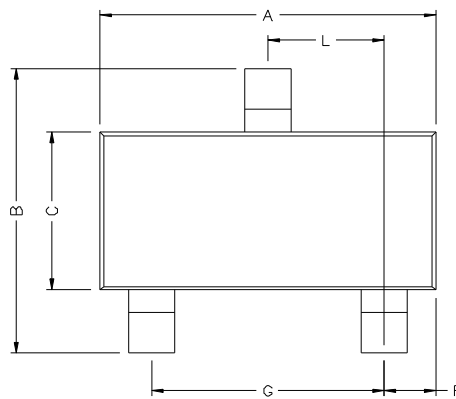
S_{21e}-FREQUENCY
CONDITION $V_{CE} = 10\text{ V}$
 $I_c = 20\text{ mA}$



S_{12e}-FREQUENCY
CONDITION $V_{CE} = 10\text{ V}$
 $I_c = 20\text{ mA}$



■ SOT23-3L



DIMENSIONS (mm are the original dimensions)

| UNIT | A | B | C | D | E | F | G | H | K | J | L | M |
|------|------|------|------|------|------|------|-----|------|------|------|------|-----|
| mm | 2.70 | 2.65 | 1.50 | 0.35 | 0 | 0.45 | 1.9 | 1.00 | 0.10 | 0.40 | 0.85 | 0° |
| | 3.10 | 2.95 | 1.70 | 0.50 | 0.10 | 0.55 | | 1.30 | 0.20 | - | 1.15 | 10° |